



Micro Commercial Components

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20736 Marilla Street Chatsworth
CA 91311
Phone: (818) 701-4933
Fax: (818) 701-4939

1N5817G THRU 1N5819G

1.0 Amp Schottky Barrier Rectifier 20 to 40 Volts

Features

- Metal silicon junction, majority carrier conduction
- For surface mount application
- Low power loss, high efficiency
- High current capability, low forward voltage drop.
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- High temperature soldering guaranteed: 250°C/10 seconds at terminals

Maximum Ratings

- Case: Molded Glass Body
- Operating Temperature: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Typical Thermal Resistance; 30°C/W Junction To Lead
75°C/W Junction To Ambient

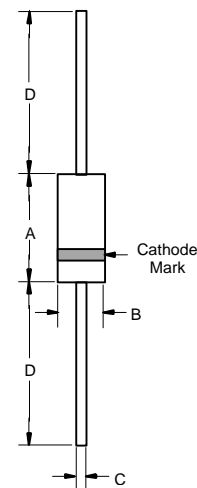
MCC Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
1N5817G	20V	14V	20V
1N5818G	30V	21V	30V
1N5819G	40V	28V	40V

Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current	$I_{F(AV)}$	1.0A	$T_A = 25^\circ\text{C}^*$
Peak Forward Surge Current	I_{FSM}	30A	8.3ms, half sine
Maximum Instantaneous Forward Voltage	V_F	0.5V	$I_{FM} = 1.0\text{A}; T_J = 25^\circ\text{C}^*$
Maximum DC Reverse Current At Rated DC Blocking Voltage	I_R	1.0mA 10mA	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$
Typical Junction Capacitance	C_J	110pF	Measured at 1.0MHz, $V_R=4.0\text{V}$

*Pulse test: Pulse width 300 μsec , Duty cycle 1%

DO-41G



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.166	0.205	4.10	7.60	
B	0.080	0.107	2.00	3.60	Diameter
C	0.026	0.034	0.70	0.90	Diameter
D	1.000	-----	25.40	-----	

1N5817G thru 1N5819G

FIG. 1-FORWARD CURRENT DERATING CURVE

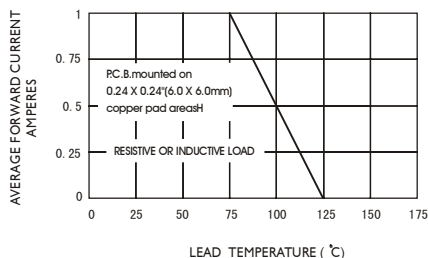


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

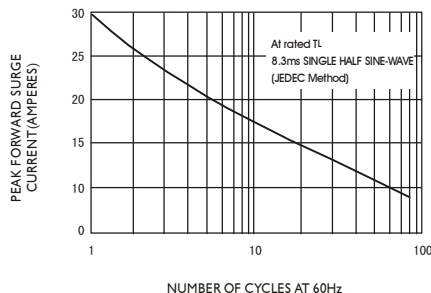


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

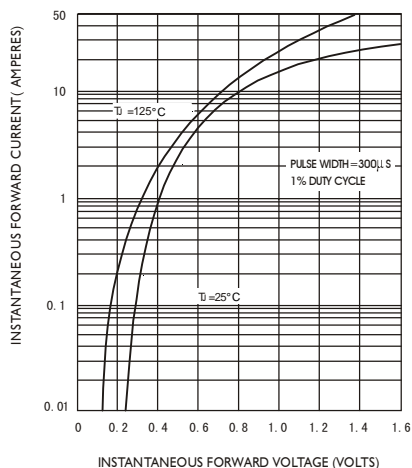


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

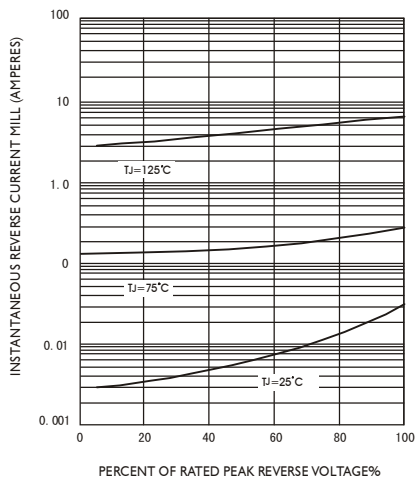


FIG. 5-TYPICAL JUNCTION CAPACITANCE

